TOSHIBA Transistor Silicon NPN Triple Diffused Type (Darlington)

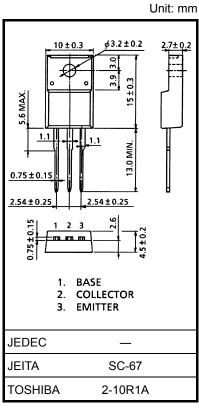
# 2SD2079

High-Power Switching Applications
Hammer Drive, Pulse Motor Drive Applications

- High DC current gain:  $h_{FE(1)} = 2000 \text{ (min)}$
- Low saturation voltage:  $V_{CE (sat) (1)} = 1.5 \text{ V (max)}$
- Complementary to 2SB1381.

### Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	100	V	
Collector-emitter voltage		V <sub>CEO</sub>	100	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	IC	5	Α	
	Pulse	I <sub>CP</sub>	8		
Base current		ΙΒ	0.5	Α	
Collector power dissipation	Ta = 25°C	D-	2.0	W	
	Tc = 25°C	P <sub>C</sub>	30		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



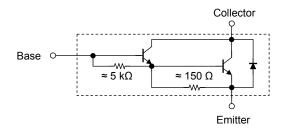
Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

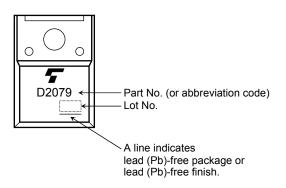
### **Equivalent Circuit**

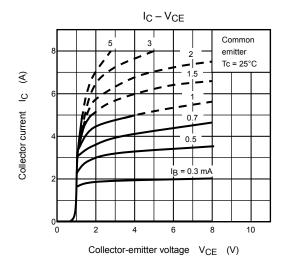


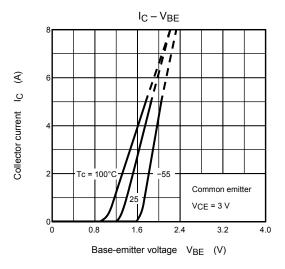
## Electrical Characteristics (Tc = 25°C)

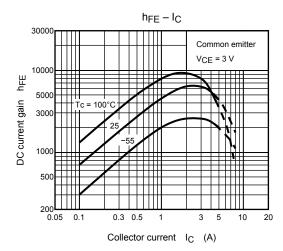
Characteristics Symbol Te		Test Condition	Min	Тур.	Max	Unit		
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 100 V, I <sub>E</sub> = 0	_	_	100	μΑ	
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0	_	_	2.5	mA	
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 30 mA, I <sub>B</sub> = 0	100	_	_	V	
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 3 A	2000	_	15000		
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 5 A	1000	_	_		
Collector-emitter saturation voltage		V <sub>CE</sub> (sat) (1)	I <sub>C</sub> = 3 A, I <sub>B</sub> = 6 mA	_	1.1	1.5	V	
		V <sub>CE</sub> (sat) (2)	I <sub>C</sub> = 5 A, I <sub>B</sub> = 20 mA	_	1.3	2.5	V	
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 3 A, I <sub>B</sub> = 6 mA	_	1.7	2.5	٧	
Switching time Storage	Turn-on time	t <sub>on</sub>	Output  Output  Output $CC$	_	1.0	_	μs	
	Storage time	t <sub>stg</sub>		ı	4.0	_		
	Fall time	t <sub>f</sub>		_	2.5			

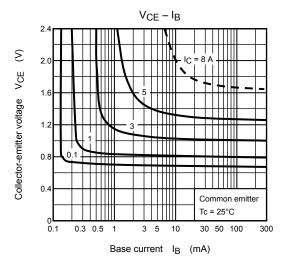
### Marking

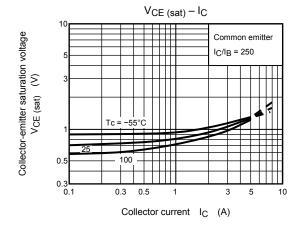


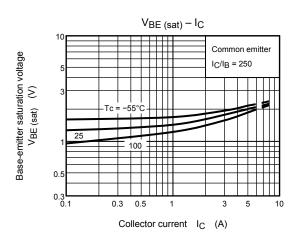


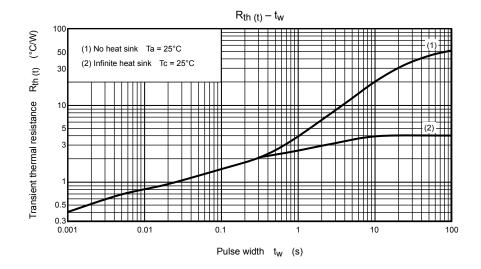


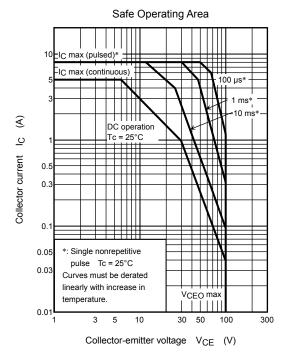


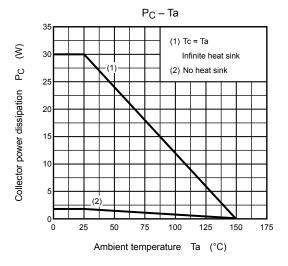












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